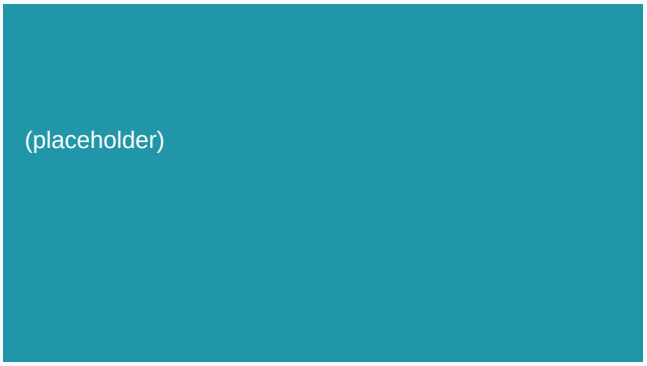
IRF540N (TO-220-3) MOSFET

Slug: irf540n-to-220-3-mosfet-pack-of-2-ics



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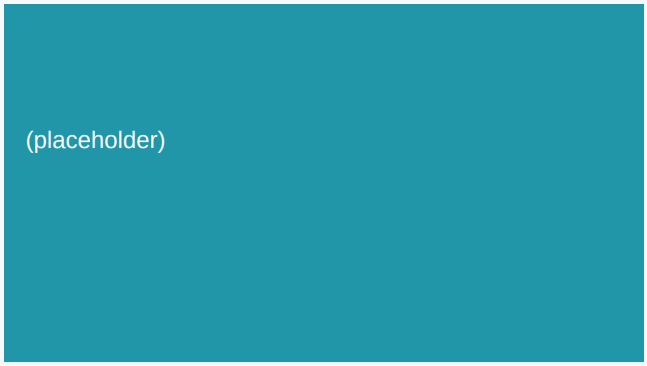

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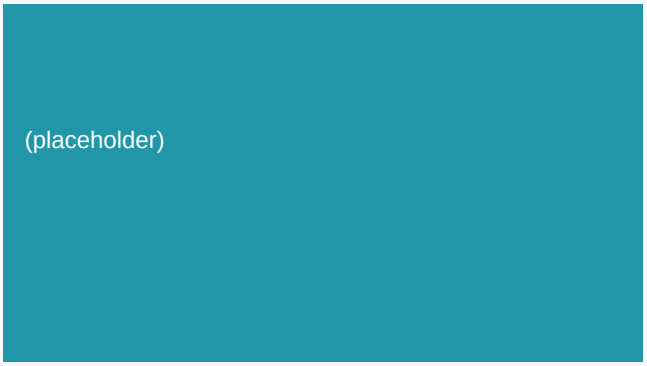
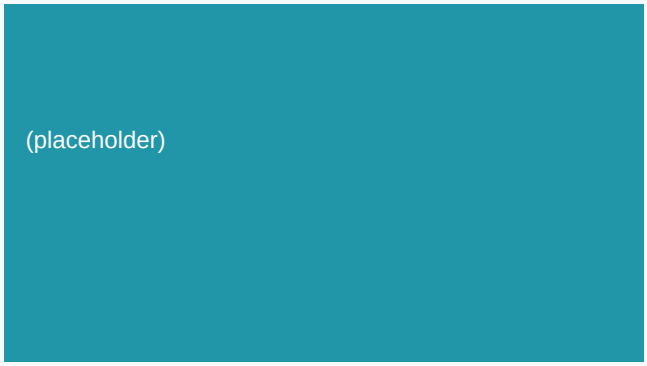


DETAIL



PINOUT

TECHNICAL SPECIFICATIONS & SUMMARY

[Mosfet] The IRF540N (TO-220-3) MOSFET from International Rectifier is 100V single N channel HEXFET power MOSFET in TO-220AB package. This MOSFET features extremely low on-resistance per silicon area, dynamic dv/dt rating, rugged, fast switching and fully avalanche rated as a result, power MOSFET is well known to provide extremely efficiency and reliability which can be used in wide variety of applications. Features: Drain to source voltage Vds is 100V Gate to source voltage is +/-20V On Resistance Rds(on) of 44mohm at Vgs of 10V Power dissipation Pd of 130W at 25 deg C Continuous drain current Id of 33A at Vgs 10V and 25 deg C Operating junction temperature range from -55 deg C to 175 deg C Applications: Power Management, Industrial, Portable Devices, Consumer Electronics. Package Includes: 1 x IRF540N (TO-220-3) MOSFET

UNIT PRICE (EX. GST)
Rs. 25

WITH 18% GST
Rs. 30

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